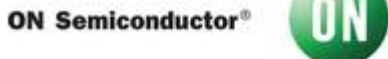

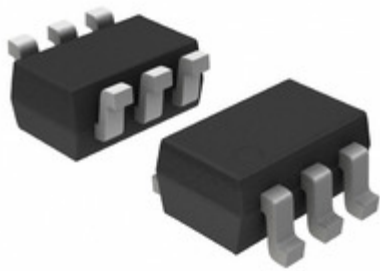










|   |  |
|---|--|
|  | <h2 style="color: #E67E22;">NTJS4151PT1G</h2>  |
|   | <p><b>Hersteller-Teilenummer:</b> <a href="#">NTJS4151PT1G</a></p> <p><b>Hersteller / Marke:</b> <a href="#">AMI Semiconductor / ON Semiconductor</a></p> <p><b>Teil der Beschreibung:</b> MOSFET P-CH 20V 3.3A SC-88</p> <p><b>Datenblätter:</b>  <a href="#">NTJS4151PT1G.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 277299 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p> |
|  |  |
| <p>Image may be representation.<br/>See specs for product details.</p>            |  |

### Spezifikationen

|  |   |
|--|---|
| Teilenummer                                      | NTJS4151PT1G  |
| Hersteller                                       | AMI Semiconductor / ON Semiconductor  |
| Beschreibung                                     | MOSFET P-CH 20V 3.3A SC-88  |
| Kategorie  | <a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> , |
| Teilstatus                                       | 277299 pcs Stock  |
| Serie  | -   |
| Technologie                                      | MOSFET (Metal Oxide)  |
| Betriebstemperatur                               | -55°C ~ 150°C (TJ)  |
| Befestigungsart                                  | Surface Mount   |
| Verpackung / Gehäuse                             | 6-TSSOP, SC-88, SOT-363   |
| Supplier Device-Gehäuse                          | SC-88/SC70-6/SOT-363  |
| Verlustleistung (max)                            | 1W (Ta)   |
| Typ FET  | P-Channel   |
| FET-Merkmal                                      | -   |
| Drain-Source-Spannung (Vdss)                     | 20V   |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 3.3A (Ta)   |
| Rds On (Max) @ Id, Vgs                           | 60 mOhm @ 3.3A, 4.5V  |
| VGS (th) (Max) @ Id                              | 1.2V @ 250µA  |
| Gate Charge (Qg) (Max) @ Vgs                     | 10nC @ 4.5V   |
| Eingabekapazität (Ciss) (Max) @ Vds              | 850pF @ 10V   |
| Antriebsspannung (Max Rds On, Min Rds On)        | 1.8V, 4.5V  |
| Vgs (Max)  | ±12V  |
| Verpackung                                       | Original-Reel®  |



















































NTJS4151PT1G ist neu im Original, Suche NTJS4151PT1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTJS4151PT1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTJS4151PT1G: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

|   |  |  |  |
|---|--|--|--|
|  <p><b>NTJS4151PT1</b><br/>AMI Semiconductor / ON Semiconductor<br/>MOSFET P-CH 20V 3.3A SOT-363</p> |  <p><b>NTJS4405NT4</b><br/>AMI Semiconductor / ON Semiconductor<br/>MOSFET N-CH 25V 1A SOT-363</p>    |  <p><b>NTJS4405NT1</b><br/>AMI Semiconductor / ON Semiconductor<br/>MOSFET N-CH 25V 1A SOT-363</p>   |  <p><b>NTJS4405NT4G</b><br/>AMI Semiconductor / ON Semiconductor<br/>MOSFET N-CH 25V 1A SOT-363</p>   |
|  <p><b>NTJS4160NT1G</b><br/>AMI Semiconductor / ON Semiconductor<br/>MOSFET N-CH 30V 1.8A SC88-6</p> |  <p><b>NTJS3157NT2G</b><br/>AMI Semiconductor / ON Semiconductor<br/>MOSFET N-CH 20V 3.2A SOT-363</p> |  <p><b>NTJS3157NT2</b><br/>AMI Semiconductor / ON Semiconductor<br/>MOSFET N-CH 20V 3.2A SOT-363</p> |  <p><b>NTJS3157NT4G</b><br/>AMI Semiconductor / ON Semiconductor<br/>MOSFET N-CH 20V 3.2A SOT-363</p> |

### heiße Teile

Mehr

|  |  |  |   |  |
|--|--|--|---|--|
|  AOK18N65L        |  AQY221N1             |  B82498F3121J     |  BAT46AWFILM          |  CKG45NX7R1C226MT009W |
|  DMN32D2LFB4-7-HN |  FC804-TL             |  GDZ8V2B-V-GS08   |  GJM1555C1H5R4WB01D   |  GRM2165C1H470GZ01D   |
|  ICS9LPRS501PKLFT |  LTC1628CG-SYNC#TRPBF |  LTC2360HS6#TRPBF |  MC10E116FNR2         |  MMBZ5236B-RTK/P      |
|  MMD7N02ZR2G      |  NTJD1155LT1G         |  NTJD2152PT1      |  NTJD2152PT1G         |  NTJD3115PT1G         |
|  NTJD3158CT1G     |  NTJD3158CT2G         |  NTJD4001NT1G     |  NTJD4001NT2G         |  NTJD4105CT1G         |
|  NTJD4105CT2G     |  NTJD4152PT1          |  NTJD4152PT1G     |  NTJD4158CT1G         |  NTJD4158CT2G         |
|  NTJD4401NT1      |  NTJD4401NT1G         |  NTJD4401NT2      |  NTJD5121NT1G         |  NTJD5121NT2G         |
|  NTJS3151PT1G     |  NTJS3157NT1G         |  NTJS4160NT1G     |  NTJS4405NT1G         |  NTJS4405NT4G         |
|  NTJS4405UT1      |  P443C2006            |  PGH1018AM        |  PIC32MX130F064D-I/PT |  SC4509SKTRT          |
|  T931S18TMC       |  TC74LCX138FK         |  TVB270SA         |  VI-RAM-7Z1           |  VND5E050AK           |

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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